

HIGH VOLTAGE ULTRAFAST RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 A
V_{RRM}	800 V
T_j (max)	175 °C
V_F (max)	1.25 V

FEATURES AND BENEFITS

- Low forward voltage drop
- High reliability
- High surge current capability
- Soft switching for reduced EMI disturbances
- Planar technology

DESCRIPTION

The STTH208, which is using ST ultrafast high voltage planar technology, is specially suited for free-wheeling, clamping, snubbing, demagnetization in power supplies and other power switching applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			800	V
$V_{(RMS)}$	RMS voltage			560	V
$I_{F(AV)}$	Average forward current		$T_J = 60^\circ\text{C}$ $\delta = 0.5$	DO-15	2
			$T_J = 100^\circ\text{C}$ $\delta = 0.5$	SMB	2
I_{FSM}	Forward surge current $t = 8.3 \text{ ms}$			DO-15	45
				SMB	35
T_{stg}	Storage temperature range			- 50 + 175	°C
T_j	Maximum operating junction temperature			+ 175	°C

THERMAL PARAMETERS

Symbol	Parameter			Value	Unit
$R_{th(j-l)}$	Junction to lead	$L = 10 \text{ mm}$	DO-15	40	$^{\circ}\text{C/W}$
			SMB	25	
$R_{th(j-a)}$	Junction to ambient	$L = 10 \text{ mm}$	DO-15	110	

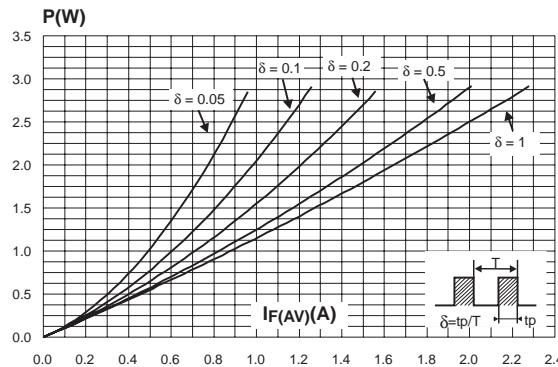
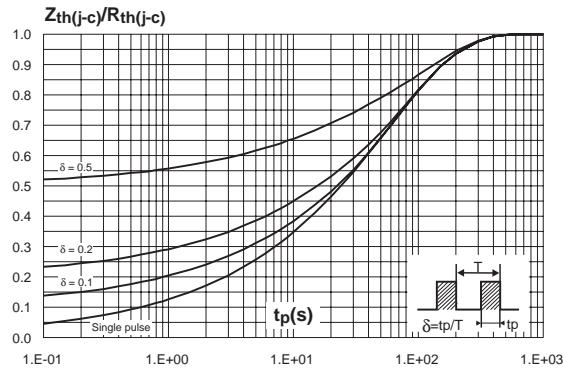
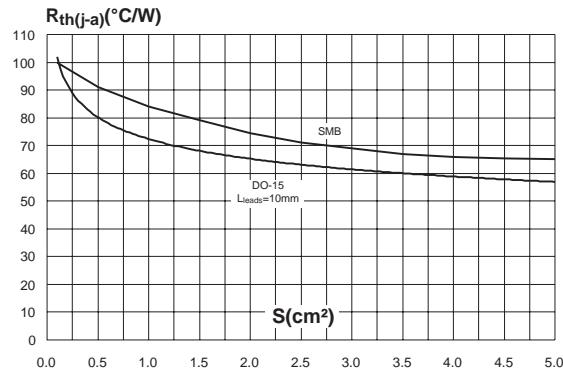
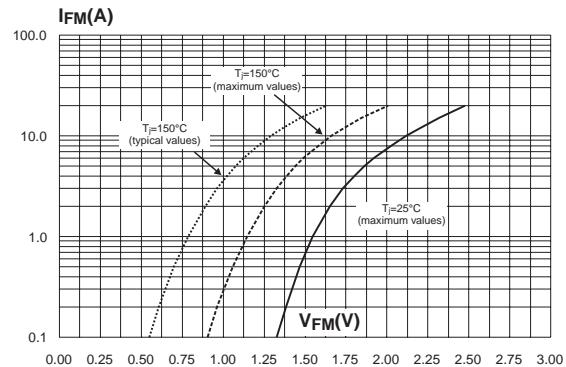
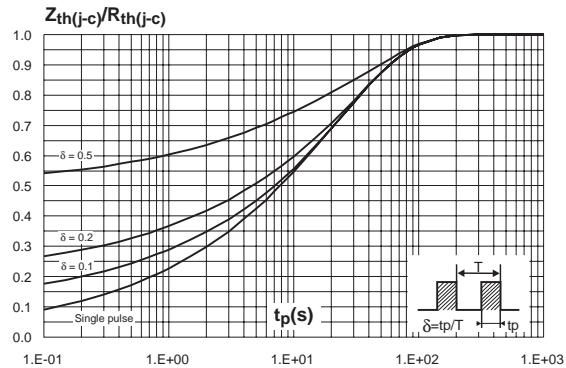
STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I_R	Reverse leakage current	$V_R = 800\text{V}$	$T_j = 25^{\circ}\text{C}$			5	μA
			$T_j = 125^{\circ}\text{C}$			50	
V_F	Forward voltage drop	$I_F = 2 \text{ A}$	$T_j = 25^{\circ}\text{C}$			1.65	V
			$T_j = 150^{\circ}\text{C}$		0.89	1.25	

To evaluate the maximum conduction losses use the following equation :
 $P = 1.05 \times I_{F(\text{AV})} + 0.10 \times I_{F(\text{RMS})}^2$

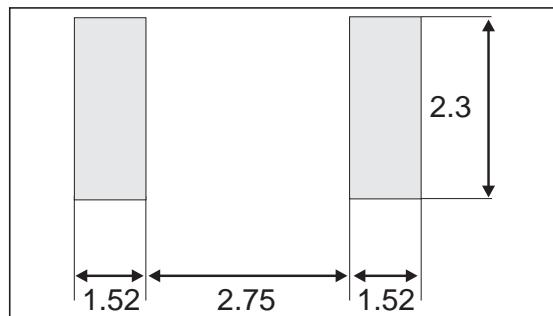
DYNAMIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 0.5 \text{ A}$ $I_{rr} = 0.25 \text{ A}$	$I_R = 1 \text{ A}$	$T_j = 25^{\circ}\text{C}$		75	ns
t_{fr}	Forward recovery time	$I_F = 2 \text{ A}$ $dI_F/dt = 50 \text{ A}/\mu\text{s}$		$T_j = 25^{\circ}\text{C}$		200	ns
V_{FP}	Forward recovery voltage	$V_{FR} = 1.1 \times V_F \text{ max}$				9	V

Fig. 1: Conduction losses versus average current.**Fig. 3-1:** Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4, $L_{leads} = 10\text{mm}$) (DO-15).**Fig. 4:** Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed circuit board FR4, copper thickness: 35 μm).**Fig. 2:** Forward voltage drop versus forward current.**Fig. 3-2:** Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4, $S=1\text{cm}^2$) (SMB).

PACKAGE MECHANICAL DATA
SMB

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	1.95	2.20	0.077	0.087
c	0.15	0.41	0.006	0.016
E	5.10	5.60	0.201	0.220
E1	4.05	4.60	0.159	0.181
D	3.30	3.95	0.130	0.156
L	0.75	1.60	0.030	0.063

FOOTPRINT (in millimeters)

PACKAGE MECHANICAL DATA
DO-15

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	6.05	6.75	0.238	0.266
B	2.95	3.53	0.116	0.139
C	26	31	1.024	1.220
D	0.71	0.88	0.028	0.035

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH208	STTH208	DO-15	0.4 g	1000	Ammopack
STTH208U	U08	SMB	0.11 g	2500	Tape & reel
STTH208RL	STTH208	DO-15	0.4 g	6000	Tape & reel

- Epoxy meets UL 94,V0

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